

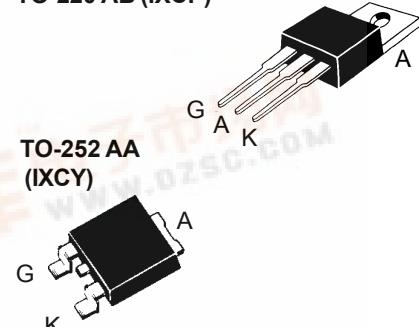


Switchable Current Regulators

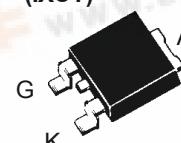
IXCP 10M35S
IXCY 10M35S
IXCP 10M45S
IXCY 10M45S
V_{AK} = 350/450 V
I_{A(P)} = 2 - 100 mA
R_{DYN} = 9 - 900 kΩ

Symbol	Test Condition	Maximum Ratings		
V _{AKR}	T _J = 25°C to 150°C	10M35S	350	V
		10M45S	450	V
V _{AGR}	T _J = 25°C to 150°C	10M35S	350	V
V _{AGR}		10M45S	450	V
V _{GK}			±20	V
I _D	T _c = 25°C		-0.3	A
P _D	T _c = 25°C		40	W
T _J			-55 ... +150	°C
T _{stg}			-55 ... +150	°C
T _L	Temperature for Soldering (max. 10 s)		260	°C
M _D	Mounting torque with screw M3 (TO-220) with screw M3.5 (TO-220)	0.45/4 0.55/5	Nm/lb.in. Nm/lb.in.	

TO-220 AB (IXCP)



TO-252 AA (IXCY)

**Pin connections**

- 1 = G, Control terminal;
- 2 and 4 = A (+) Positive terminal
- 3 = K (-), Negative terminal

Features

- Minimum of 350/450 V breakdown
- Resistor programmable current source
- 40 W continuous dissipation
- International standard packages JEDEC TO-220 and TO-252
- On/Off switchable current source

Applications

- Start-up circuits for SMPS
- Highly stable voltage sources
- Surge limiters and voltage protection
- Instantaneously reacting resetable fuses
- Soft start-up circuits

Symbol	Test Condition	Characteristic Values			
		(T _J = 25°C unless otherwise specified)	min.	typ.	max.
V _{AKR}	R _K = 300 Ω, (Fig. 4)	10M35S	350		V
		10M45S	450		V
I _{A(P)}	V _D = 10 V; R _K = 300 Ω; (Fig. 5)	7	10	15	mA
V _{G(off)}	I _D = 100 μA; V _D = 300 V I _D = 100 μA; V _D = 400 V Fig. 4	10M35S 10M45S	-5 -5		V V
I _{AV}	V _D = 300 V; V _{GK} = -10 V V _D = 400 V; V _{GK} = -10 V Fig. 4	10M35S 10M45S		25 25	μA μA
ΔV _{AK} /Δ I _{A(p)}	Dynamic resistance; V _D = 10 V R _K = 300 Ω; (Fig. 4)	10			kΩ
R _{thJC}	Thermal Resistance junction-to-case			3.1	K/W
R _{thJA}	Thermal Resistance junction-to-ambient TO-220 TO-252			80 100	K/W

IXYS

IXCP 10M35S **IXCY 10M35S**
IXCP 10M45S **IXCY 10M45S**

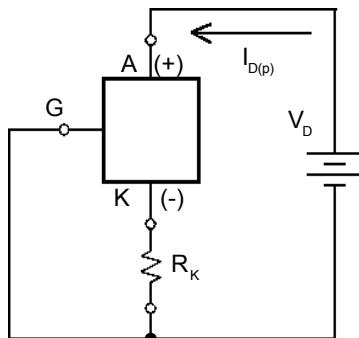


Fig. 1 Resistor R_K in series with negative pin to achieve different current levels

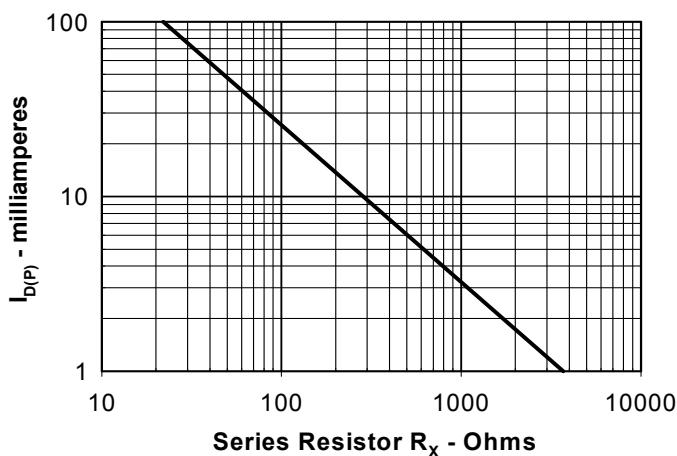


Fig. 2. Plateau current versus external resistance

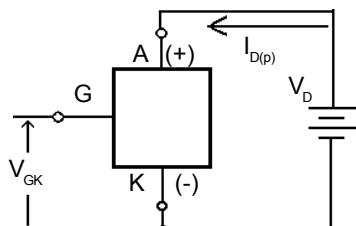


Fig. 3. Current regulator controlled by V_G

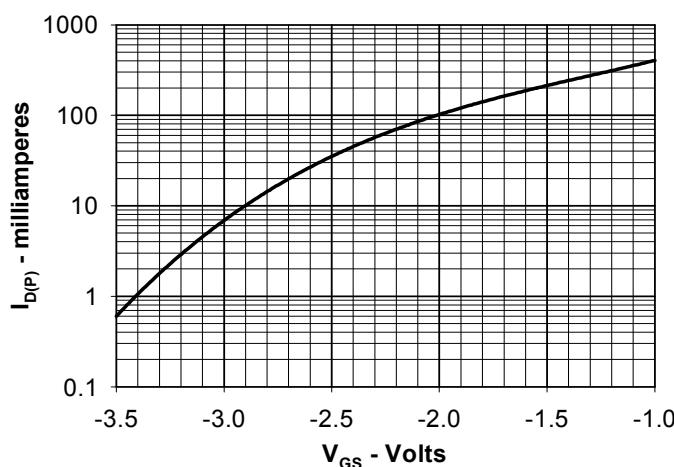
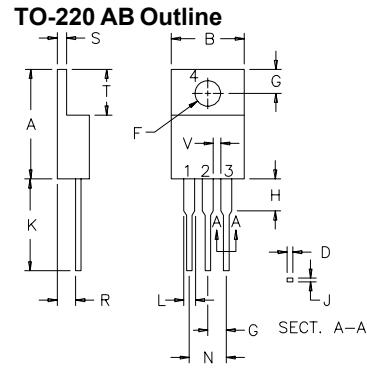
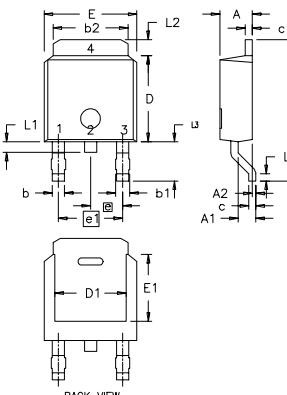


Fig. 4. Plateau current versus applied input voltage



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	14.23	16.51	.560	.650
B	9.66	10.66	.380	.420
C	3.56	4.82	.140	.190
D	0.64	0.89	.025	.035
F	3.54	4.06	.139	.161
G	2.29	2.79	.090	.110
H	—	6.35	—	.250
J	0.51	0.76	.020	.030
K	12.70	14.73	.500	.580
L	1.15	1.77	.045	.070
N	4.83	5.33	.190	.210
Q	2.54	3.42	.100	.135
R	2.04	2.49	.080	.115
S	0.64	1.39	.025	.055
T	5.85	6.85	.230	.270
V	1.15	—	.045	—

TO-252 AA Outline



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	2.19	2.38	0.086	0.094
A1	0.89	1.14	0.035	0.045
A2	0	0.13	0	0.005
b	0.64	0.89	0.025	0.035
b1	0.76	1.14	0.030	0.045
b2	5.21	5.46	0.205	0.215
c	0.46	0.58	0.018	0.023
c1	0.46	0.58	0.018	0.023
D	5.97	6.22	0.235	0.245
D1	4.32	5.21	0.170	0.205
E	6.35	6.73	0.250	0.265
E1	4.32	5.21	0.170	0.205
e	2.28	BSC	0.090	BSC
e1	4.57	BSC	0.180	BSC
H	9.40	10.42	0.370	0.410
L	0.51	1.02	0.020	0.040
L1	0.64	1.02	0.025	0.040
L2	0.89	1.27	0.035	0.050
L3	2.54	2.92	0.100	0.115

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,825,592, 4,881,106, 5,017,508, 5,040,061, 5,187,117, 5,186,715.